Quiz 11

Due 22 Aug 2021 at 23:59 Points 10 Questions 10 Time limit 30 Minutes

Instructions

- The quiz will be displayed one question at a time. After you answer a question you will not be allowed to go back and modify your answer.
- The quiz is time limited. You must complete the quiz in a single session.
- The quiz is open-book. You may check the lectures, the textbook, or even the internet.
- You may need a calculator. You can use the calculator application of your computer or smart phone.
- For multiple choice questions: Choose the best answer.
- For numerical questions: Write your answer as a decimal number with three digits of precision (ex: 1.33). Do NOT use fractions (ex: 4/3 is not accepted) and do NOT use commas (ex: 1,33 is not accepted).
- You are NOT ALLOWED to share questions and/or answers with anyone.
- Sharing questions and/or answers will be considered CHEATING.
- الله صلى الله عله وسلم: من غش الس من الله عله وسلم: Remember
- If you share questions you will get ZERO marks for this quiz.
- If you share answers you will get ZERO marks for this quiz and the next one.
- You will be able to access the questions, your answers, and the correct answers after the due date of the quiz
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Attempt history

	Attempt	Time	Score
LATEST		16 minutes	9 out of 10

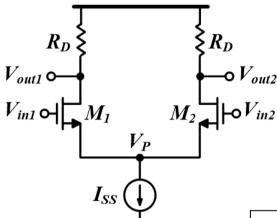
☐ Correct answers are hidden.

Score for this quiz: out of 10 Submitted 22 Aug 2021 at 23:52 This attempt took 16 minutes.

Question 1 1/1 pts

For the differential amplifier below, if a large signal Vid = Vin1 - Vin2 = -1 V is applied, then the voltage at Vout2 is approximately equal to____.

Hint: For MOS diff amp, the current is fully steered when a large signal Vid > sqrt(2)*Vov,eq is applied, where Vov,eq is the equilibrium overdrive voltage.



for — Vid the current is fully steered to M2

the
$$I_{D2} = I_{SS}$$

$$V_{out2} = V_{DD} - I_{SS}R_{D}$$

VDD - ISS*RD

O VDD		
O 0		
○ VDD - (ISS/2)*RD		

Question 2 1/1 pts

Compare the gain of a differential pair with that of a CS stage if both circuits are designed for equal power consumption, drain resistances (RD << ro), bias point (Vov), and supply voltages.

The gain of diff pair is four times that of CS

 $: I_{Cons}$ is the same $\rightarrow I_D$ of CS device = $2I_D$ of diff pair device

The gain of diff pair is half that of CS

 $g_{m} = \frac{2I_{D}}{V_{ov}} \rightarrow g_{m}CS = 2g_{m}Diff pair$

The gain of diff pair is equal to that of CS

 $A_v = g_m R_D$

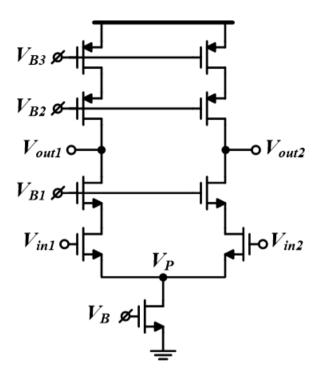
The gain of diff pair is twice that of CS

∴ the gain of diff pais is half that of CS

Question 3 1/1 pts

If VDD = 3 V and Vov for all transistors = 0.2 V, then the maximum possible peak-to-peak differential output swing is approximately equal to_____V.

Hint: You need to make sure that all transistors are in saturation. For each transistor, VDS > Vov. Note that the differential voltage swing is twice the single ended voltage swing. This is one of the important advantages of differential circuits.



3

2

0 1

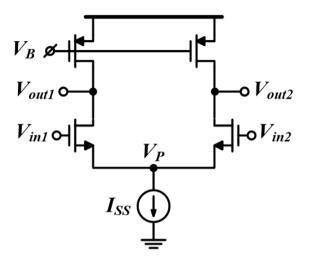
for half circuit \rightarrow V_{out} max = $V_{DD} - 2V_{ov} = 2.6$ v

$$V_{\text{out}} \min = 3 V_{\text{ov}} = 0.6$$

: max swing =
$$2.6 - 0.6 = 2 \text{ V}$$

for diff swing = $2 \text{ SE swing} = 2 \times 2 = 4$

If VA = 10 V and Vov = 0.2 V, then the differential gain is approximately equal to_____.



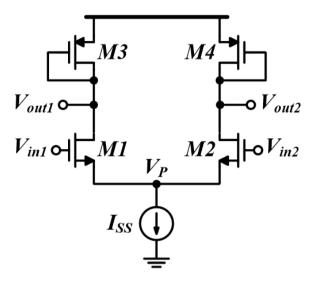
25

200

 $A_{v} = \frac{g_{m}r_{o}}{2} = \frac{2I_{D}}{V_{ov}} \times \frac{V_{A}}{I_{D}} \times \frac{1}{2} = \frac{V_{A}}{V_{ov}} = 50$

100

If mobility of NMOS is three times that of PMOS, W/L of M1,2 = 10u/1u and W/L of M3,4 = 2u/1u, then the differential voltage gain is approximately equal to_____.



2.9

4.9

3.9

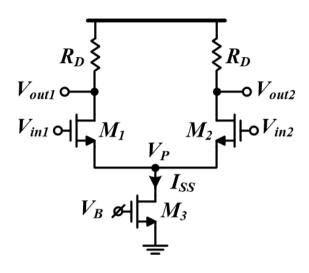
1.9

$$A_{v} = \frac{g_{mn}}{g_{mp}}$$

$$\because g_{m} = \sqrt{uC_{ox} \times \frac{W}{L} \times 2I_{D}} \rightarrow g_{m} \propto \sqrt{u} \text{ and } \sqrt{\frac{W}{L}}$$

$$g_{mn} = \sqrt{3} \times \sqrt{\frac{10u}{1u} / \frac{2u}{1u}} g_{mp} = 3.9 g_{mp}$$

If VTH = 0.4 V and Vov = 0.2 V, then the minimum allowed Vicm is approximately equal to_____V.



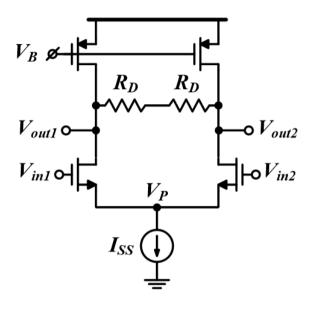
0.4

0.8

$$V_{ICM}$$
min = $V_{GS1,2} + V_{ov} = 0.4 + 0.2 + 0.2 = 0.8$ v

0.6

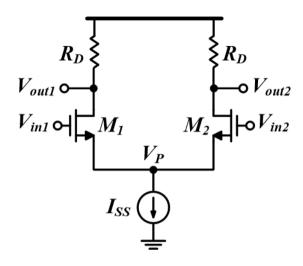
If ISS = 1 mA, VA = 10V, Vov = 0.2 V, and RD = 10 $k\Omega$, then the differential gain is approximately equal to



- **50**
- 25
- 0 100
- 200

 $A_{v} = g_{m}[(R_{D} \parallel r_{o}) \parallel r_{o}] = \frac{2I_{D}}{V_{ov}} \times 5k = 25$

For the shown differential pair assume RD << ro and the bias point (Vov) is kept constant. The maximum achievable gain is limited by____.



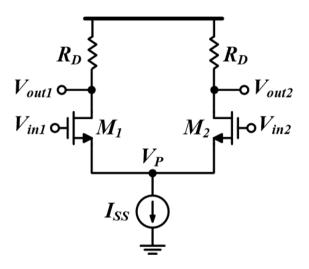
- RD
- W/L
- O VDD

 $A_v = g_m R_D \rightarrow g_m = \frac{2I_D}{V_{ov}} \rightarrow \max gain @ \max I_D \rightarrow the gain is limoted by I_{SS}$

ISS

For the differential amplifier below, if a large signal Vid = Vin1 - Vin2 = 1 V is applied, then the voltage at Vout2 is approximately equal to____.

Hint: For MOS diff amp, the current is fully steered when a large signal Vid > sqrt(2)*Vov,eq is applied, where Vov,eq is the equilibrium overdrive voltage.



○ VDD - (ISS/2)*RD

VDD

O VDD - ISS*RD

for + Vid the current is fully steered to M1

the
$$I_{D2} = 0$$

 $V_{out2} = V_{DD} - 0 = V_{DD}$

If VDD = 3 V, ISS = 100 uA, VTH = 0.4 V, Vov = 0.2V, and RD = $20k\Omega$, then the maximum allowed common mode input voltage is approximately equal to_____V.

Hint: You need to make sure that M1,2 are in sat. Note that current splits equally at equilibrium.

